

# Self-Excitation Type Semi-Regulated Switching Regulator (110W Output)

#### Overview

The STK730-010 incorporates on-chip all the power switching, amplifier, error detection and overcurrent protection circuits required in a self-excitation type semi-regulated off-line switching regulator. As a result, it can be used in the design of switching power supplies with minimal number of external components. Furthermore, the adoption of MOSFET power switching elements supports a higher oscillator frequency than that possible with bipolar transistors. This allows smaller pulse transformers and capacitors to be used, making it possible to construct miniature power supply systems.

### **Applications**

- CRT/CTV power supplies
- Office automation equipment power supplies

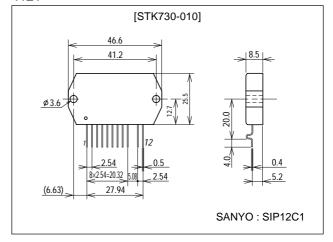
#### **Features**

- Power MOSFET devices
- Ideal for semi-regulated control switching supplies
- Error detection circuit on-chip ( $40.5 \pm 0.5$ V set reference voltage)
- Overcurrent protection circuit on-chip
- Pin compatible with all other devices in the same series of devices with 110 to 280W power ratings
- Higher oscillator frequency allows the use of smaller pulse transformers
- IMST substrate acts as an electromagnetic shield, making low-noise designs possible

### **Package Dimensions**

unit:mm

4121



### **Specifications**

**Maximum Ratings** at  $Ta = 25^{\circ}C$ ,  $Tc=25^{\circ}C$  unless otherwise specified

		•		
Parameter	Symbol	Conditions	Ratings	Unit
Operating substrate temperature	Tc max	Recommended value is 105°C	115	°C
AC input voltage	V <sub>AC</sub>	Specified test circuit	140	Vrms
Operating temperature	Topr		-10 to +85	°C
Storage temperature	Tstg		-30 to +115	°C
Maximum output power	Wo max	Specified test circuit, V <sub>O</sub> =135V	110	W

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Parameter	Symbol	Conditions	Ratings	Unit
[TR1]				
Drain current	I <sub>D</sub>	Refert to ASO characteristics for overcurrent condition.	6	Α
Pulse drain current	I <sub>D(pulse)</sub>	Refer to ASO characteristics for overcurrent condition.	20	Α
Drain reverse current	I <sub>DR</sub>		6	Α
Gate-source voltage	V <sub>GSS</sub>		±30	V
Allowable power dissipation	PD		78.1	W
Chip junction temperature	Tj max		150	°C
Thermal resistance	θј-с		1.6	°C/W
[ZD1]	•			
Allowable power dissipation	P <sub>ZD1</sub>		500	mW
Chip junction temperature	Tj(ZD1)max		125	°C
Thermal resistance	θj-c(ZD1)		0.2	°C/W

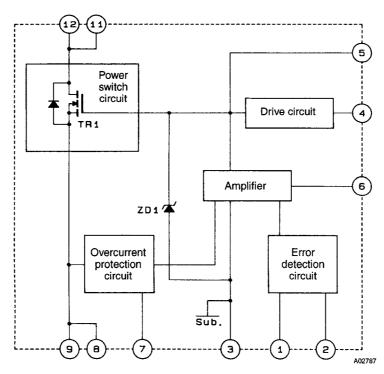
#### Allowable Operating Ranges at Ta = 25°C

Parameter	Symbol Condition		ns Ratings		
Pin 4 input voltage	٧4		±8 to ±24	V	
Oscillator frequency	fosc		20 to 120	kHz	

#### **Operating Characteristics** at Ta = 25°C, Tc=25°C unless otherwise specified, specified test circuit

Parameter	Symbol	Conditions	Ratings			Unit
	Symbol	Conditions	min	typ	max	Uill
Output voltage setteing		I <sub>IN</sub> =8mA	40.0	40.5	41.0	V
Output voltage temperature coefficient		Tc=0 to 105°C, I <sub>IN</sub> =8mA		7		mV/°C
[TR1]	•		•			•
Drain-source breakdown voltage	V(BR)DSS	I <sub>D</sub> =10mA, V <sub>GS</sub> =0V	500			V
Gate-source cutoff voltage	V <sub>GS(off)</sub>	I <sub>D</sub> =1mA, V <sub>DS</sub> =10V	2.0		3.0	V
ON resistance	R <sub>DS(on)</sub>	I <sub>D</sub> =2.5A, V <sub>GS</sub> =10V		1.4	1.8	Ω
Input capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHz		800		pF
[ZD1]						
Zener voltage	٧z	I <sub>Z</sub> =5mA	23.7		26.3	V

# **Block Diagram**

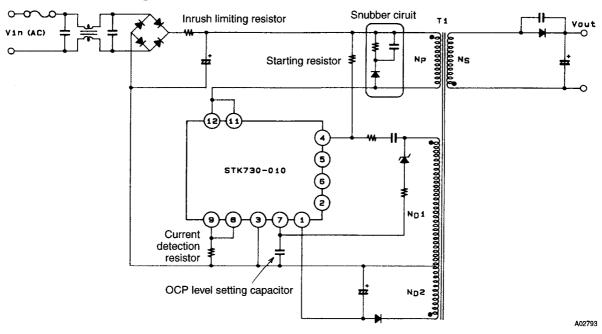


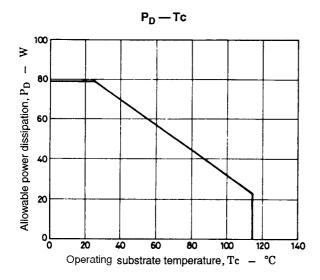
The back surface of the IC is not an insulator, and is effectively at pin 3 potential.

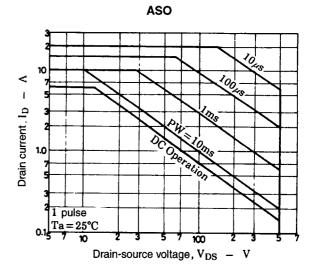
#### **Pin Functions**

Number	Function			
1	Vref (40.5V typ) input			
2	Error detection level			
3	Ground			
4	Drive voltage input			
5	TR1 gate			
6	Amplifier circuit control			
7	OCP setting level input			
8	TR1 source			
9	TIXT SOULCE			
11	TR1 drain			
12	INTUIAIII			

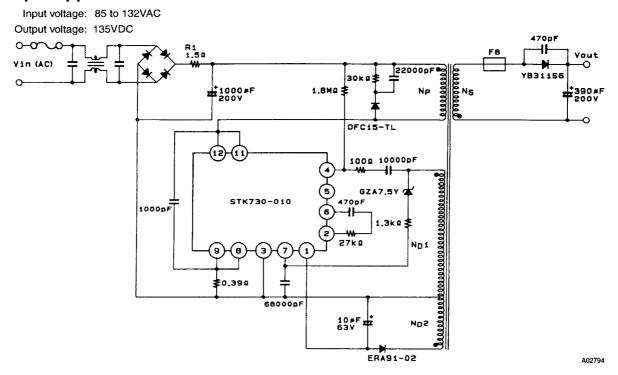
# **Circuit Function Diagram**



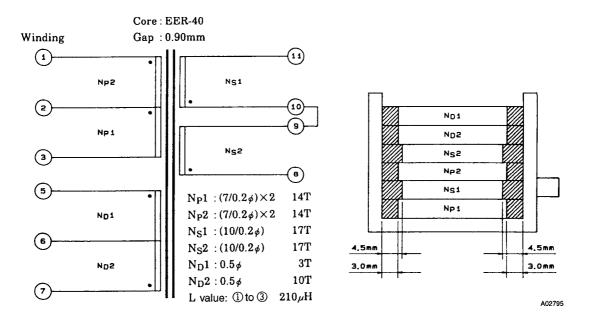


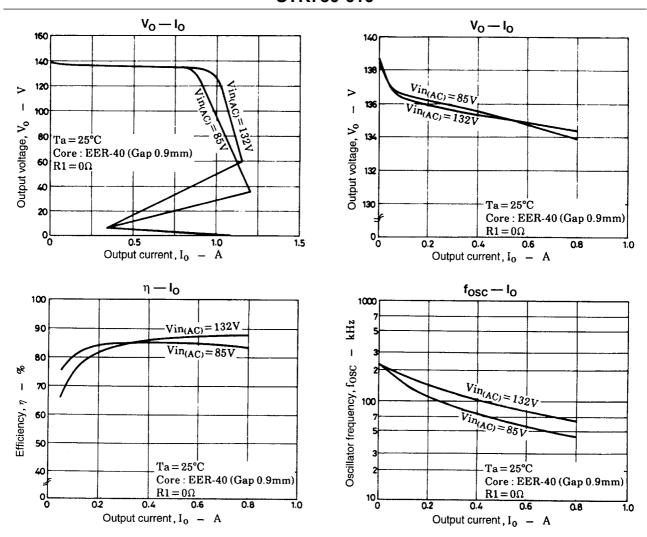


### **Sample Application Circuit**



### **Pulse Transformer Specifications**





## **Series Organization**

The devices form a series with varying output power ratings.

	Maximum ratings			Operating characteristics				
Device	V <sub>DSS</sub> [V]	Tstg [°C]	Tc max [°C]	Tj max [°C]	I <sub>D</sub> [A]	Input voltage [V]	Oputut power [W]	ON resistance [Ω]
STK730-010			+115	115 +150	6.0	85 to 132	110	1.4
STK730-020					8.0		145	0.8
STK730-030	500	-30 to - +115			10.0		180	0.7
STK730-040					12.0		210	0.55
STK730-050					15.0		280	0.3
STK730-060					3.0	170 to 264	110	5.0
STK730-070	900				5.0		180	3.0
STK730-080	900				6.0		210	2.0
STK730-090					8.0		280	1.2

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